

Ultra Low Power Electronics for Undetectable ASTs

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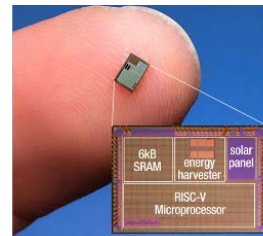
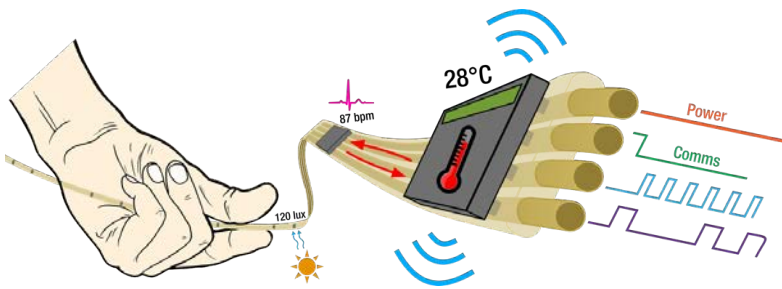
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Advanced Smart Textiles (ASTs) are Power-Limited

- ▶ Any AST using conventional chips will need a “puck” to house batteries and electronics somewhere in the system
- ▶ Get the puck out! → lower power to microwatt range
- ▶ To integrate in textiles or fiber, we need a distributed network of components with integrated power & data

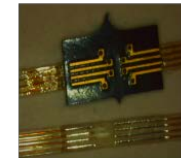


**Segment SoC
(System on Chip)**

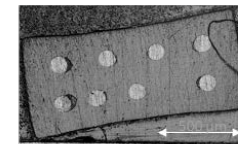
- 1.5 nW to 10 nW
- MCU, SRAM, bus, DC-DC, harvesting, temp sensor



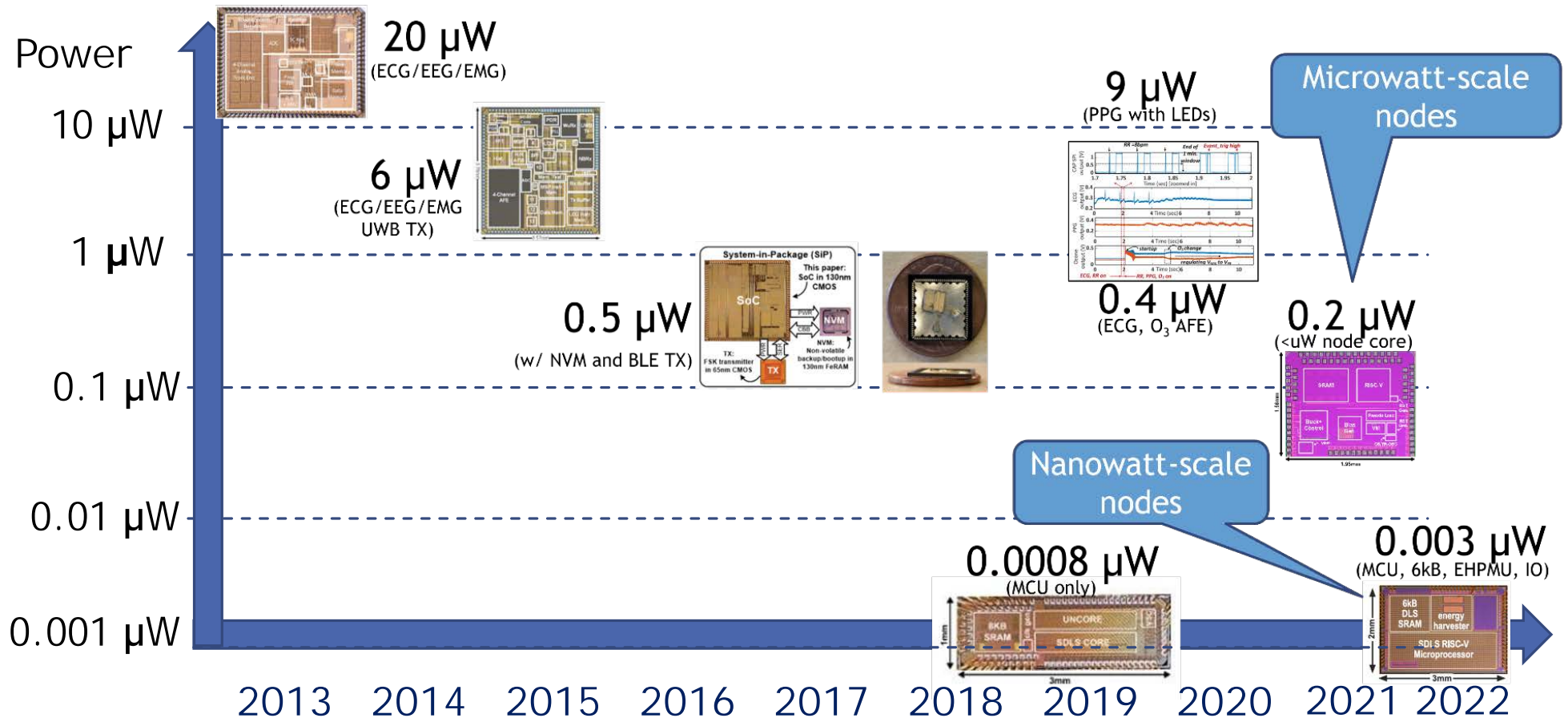
On
interposer



**Fiber
Development
(MIT-LL)**



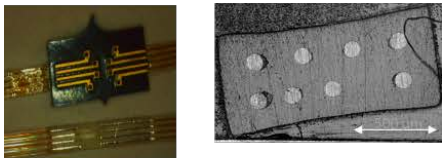
UVA Systems-on-Chip: Do a lot for μ Ws!



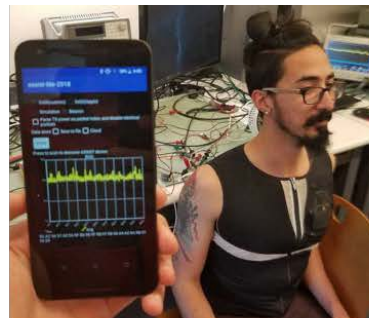
Integration with Fiber and Fabrics

- ▶ Components placed around garment
→ Multiple techniques
- ▶ Collaborations to show variety of integrated components and technology options

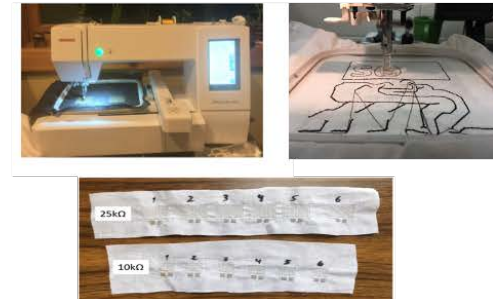
Into Fiber: integrated bus and power
(MIT-LL)



Into textiles: sensors, energy harvesting, interconnect, antennas, energy storage
(ASSIST Center, NCSU)

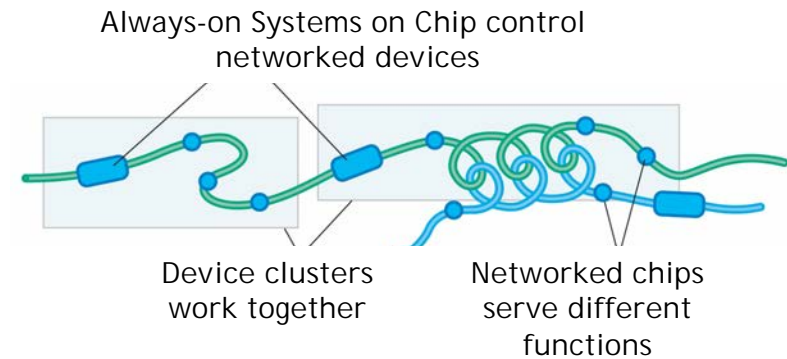


Embroidered components: sensors, energy harvesting, textile actuators
(Sarah Sun, UVA)

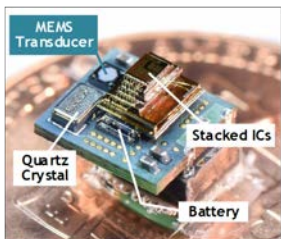


System integration

- ▶ Distributed network of components with integrated power & data
- ▶ Components support IARPA use case at microwatts or below

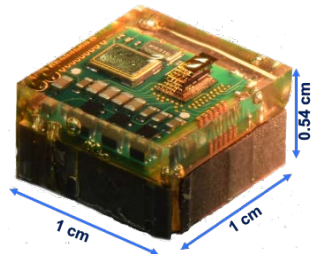


Sensing: Audio sensing, imaging w/ detection (Dave Wentzloff, UMich)
(Dennis Sylvester, UMich)



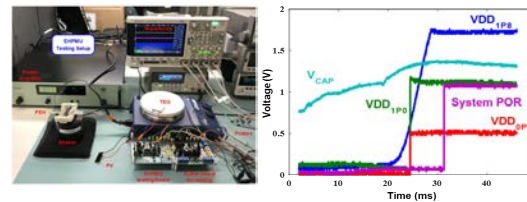
- 142nW Voice Activation
- Analog front end, mic
- Neural net classifier
- mm-scale imaging

Sensing: GPS (Dave Wentzloff, UMich)



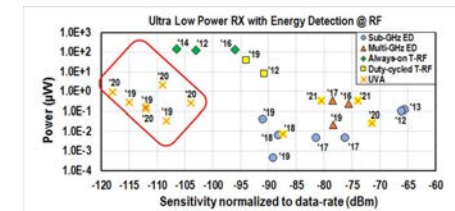
- GPS AFE: 13 μ W to 10mW
- 100ms RF recording time
- 32 satellite search
- 28 days of fixes stored
- Battery or PV powered

Power: DC-DC conversion, energy storage, energy harvesting (UVA)



- ~90% efficient at nW to μ W
- Multiple in, multiple out
- Store: battery or supercap
- Harvest: light, temp, motion

Data, memory, processing, communications (UVA)



- Lowest power SRAM: <nW
- Non-volatile memory: μ W
- Digital acceleration and processing
- Wakeup RX: -110dBm at <100nW